2-input NAND gate

Rev. 1 — 16 September 2013

Product data sheet

1. General description

The 74HC1G00-Q100; 74HCT1G00-Q100 is a single 2-input NAND gate. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
 - For 74HC1G00-Q100: CMOS level
 - For 74HCT1G00-Q100: TTL level
- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

3. Ordering information

Table 1.Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74HC1G00GW-Q100	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads;	SOT353-1				
74HCT1G00GW-Q100			body width 1.25 mm					
74HC1G00GV-Q100	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753				
74HCT1G00GV-Q100	-							

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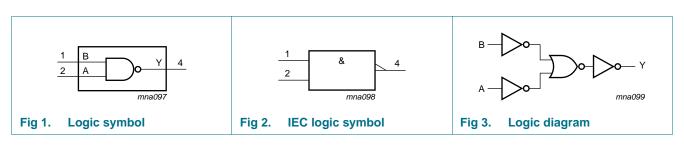
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4. Marking

Table 2. Marking codes	
Type number	Marking ^[1]
74HC1G00GW-Q100	НА
74HCT1G00GW-Q100	ТА
74HC1G00GV-Q100	H00
74HCT1G00GV-Q100	Т00

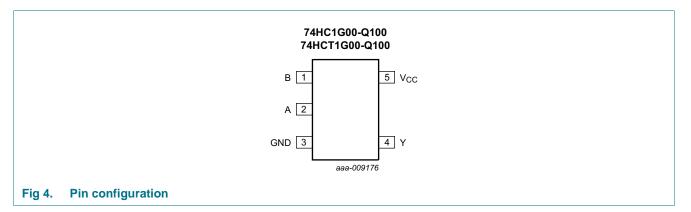
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

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Table 3.	Pin description	
Symbol	Pin	Description
В	1	data input
A	2	data input
GND	3	ground (0 V)
Y	4	data output
V _{CC}	5	supply voltage

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7. Functional description

Table 4. Function table

H = *HIGH* voltage level; *L* = *LOW* voltage level

Input		Output
Α	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V). [1]

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	V_{I} < -0.5 V or V_{I} > V_{CC} + 0.5 V	-	±20	mA
I _{OK}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
Ι _Ο	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±12.5	mA
I _{CC}	supply current		-	25	mA
I _{GND}	ground current		-25	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C$ to +125 $^{\circ}C$	[2] _	200	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] Above 55 °C, the value of P_{tot} derates linearly with 2.5 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74HC1	74HC1G00-Q100			74HCT1G00-Q100		
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	-	139	-	-	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

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10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

Symbol	Parameter	Conditions	-40	°C to +	85 °C	–40 °C	Unit	
			Min	Тур	Max	Min	Max	
For type	74HC1G00-Q100							
V _{IH} HIGH-level in voltage	HIGH-level input	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	V
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	V
V _{IL} LOW-level in voltage	LOW-level input	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	V
V _{он}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	voltage	I_{O} = -20 μ A; V_{CC} = 2.0 V	1.9	2.0	-	1.9	-	V
		I_O = -20 μ A; V_{CC} = 4.5 V	4.4	4.5	-	4.4	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	V
		$I_{O} = -2.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.13	4.32	-	3.7	-	V
		I_{O} = -2.6 mA; V_{CC} = 6.0 V	5.63	5.81	-	5.2	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$						
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	V
		I_{O} = 2.0 mA; V_{CC} = 4.5 V	-	0.15	0.33	-	0.4	V
		I_{O} = 2.6 mA; V_{CC} = 6.0 V	-	0.16	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	1.0	-	1.0	μA
I _{CC}	supply current	$V_I = V_{CC} \text{ or GND}; I_O = 0 \text{ A};$ $V_{CC} = 6.0 \text{ V}$	-	-	10	-	20	μA
Cı	input capacitance		-	· 1.5	-	-	-	pF
For type	74HCT1G00-Q100							
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	V
V _{он}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	voltage	I_{O} = -20 μ A; V_{CC} = 4.5 V	4.4	4.5	-	4.4	-	V
		I_{O} = -2.0 mA; V_{CC} = 4.5 V	4.13	4.32	-	3.7	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	voltage	$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	V
		I_{O} = 2.0 mA; V_{CC} = 4.5 V	-	0.15	0.33	-	0.4	V
l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	1.0	-	1.0	μA

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Voltages a	re referenced to GND (g	round = 0 V). All typical values are Conditions	$= measured at T_{amb} = 25$ -40 °C to +85 °C			°C. _40 °C	Unit	
			Min	Тур	Мах	Min	Мах	
I _{CC}	supply current		-	-	10	-	20	μA
ΔI_{CC}	additional supply current	per input; V _{CC} = 4.5 V to 5.5 V; V _I = V _{CC} - 2.1 V; I _O = 0 A	-	-	500	-	850	μA
CI	input capacitance		-	1.5	-	-	-	pF

Table 7. Static characteristics ...continued

11. Dynamic characteristics

Table 8. Dynamic characteristics

GND = 0 V; $t_r = t_f \le 6.0$ ns; All typical values are measured at $T_{amb} = 25$ °C. For test circuit, see Figure 6

Symbol	Parameter	Conditions		–40 °C to +85 °C			–40 °C	Unit	
				Min	Тур	Max	Min	Max	
For type	74HC1G00-Q100					1		1	
t _{pd}	propagation delay	A and B to Y; see Figure 5	<u>[1]</u>						
		$V_{CC} = 2.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	25	115	-	135	ns
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	9	23	-	27	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	7	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	8	20	-	23	ns
C _{PD}	power dissipation capacitance	$V_I = GND$ to V_{CC}	[2]	-	19	-	-	-	pF
For type	74HCT1G00-Q100								
t _{pd}	propagation delay	A and B to Y; see Figure 5	<u>[1]</u>						
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	12	24	-	27	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	10	-	-	-	ns
C _{PD}	power dissipation capacitance	V_{I} = GND to V_{CC} – 1.5 V	[2]	-	21	-	-	-	pF

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] $~C_{PD}$ is used to determine the dynamic power dissipation P_D (\muW).

 P_{D} = $C_{PD} \times V_{CC}{}^{2} \times f_{i}$ + \sum ($C_{L} \times V_{CC}{}^{2} \times f_{o}$) where:

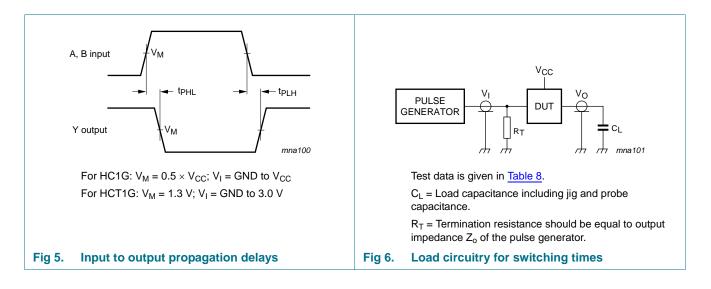
 f_i = input frequency in MHz; f_o = output frequency in MHz

 C_L = output load capacitance in pF

$$\label{eq:VCC} \begin{split} V_{CC} &= \text{supply voltage in Volts} \\ \sum \left(C_L \times V_{CC}^2 \times f_0 \right) = \text{sum of outputs} \end{split}$$

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12. Waveforms



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13. Package outline

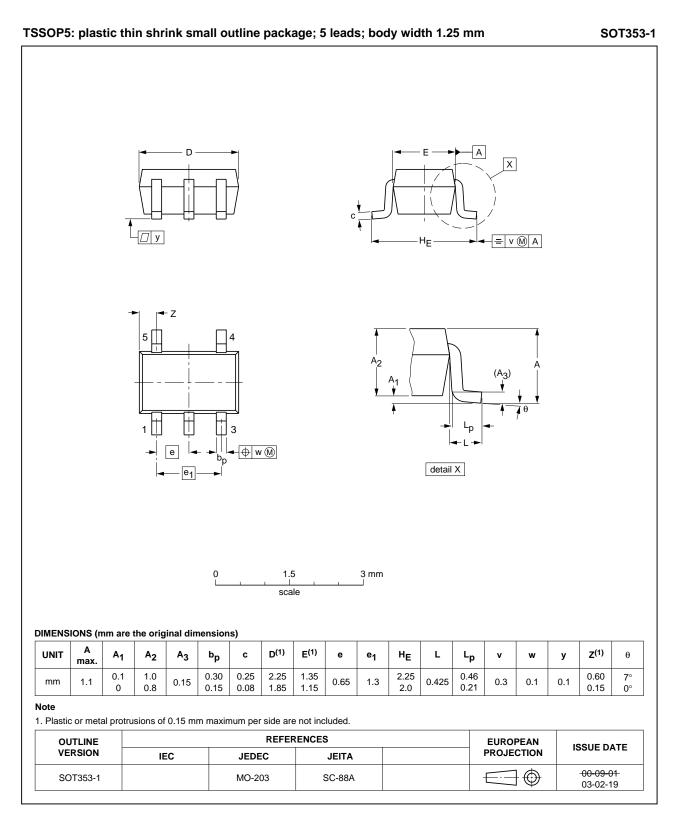


Fig 7. Package outline SOT353-1 (TSSOP5)

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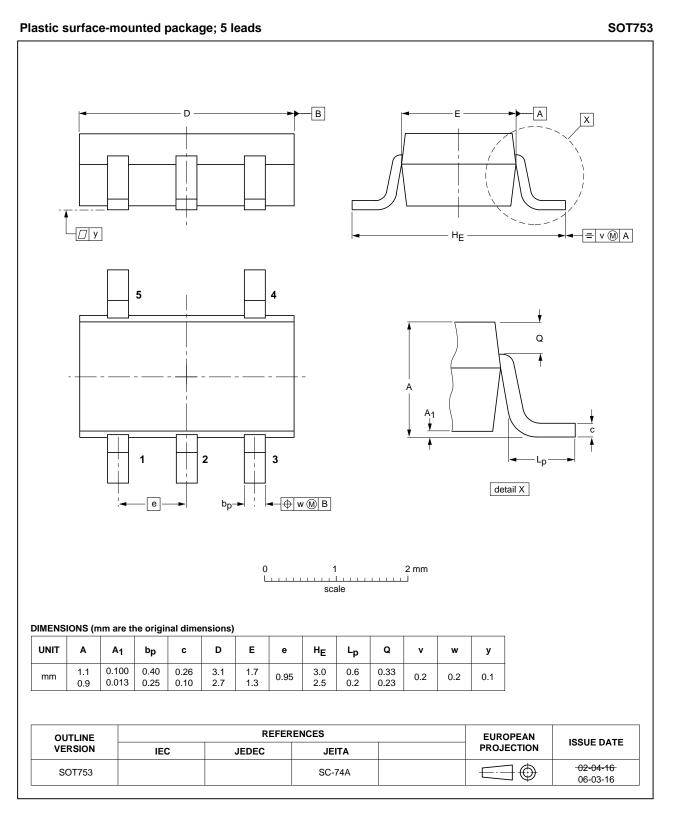


Fig 8. Package outline SOT753 (SC-74A)

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14. Abbreviations

Table 9.	Abbreviations				
Acronym	Description				
CMOS	Complementary Metal Oxide Semiconductor				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
HBM	Human Body Model				
MIL	Military				
MM	Machine Model				
TTL	Transistor-Transistor Logic				

15. Revision history

able 10. Revision history								
Document ID	Release date	Data sheet status	Change notice	Supersedes				
74HC_HCT1G00_Q100 v.1	20130916	Product data sheet	-	-				

16. Legal information

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